RoHS Compliant

Serial ATA Flash Drive

SFD25A-M HighSpeed Product Specifications

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Version 1.8



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Features:

Compliance with SATA Revision 3.1

- SATA 6.0 Gbps interface
- Backward compatible with SATA 1.5 and 3.0 Gbps interfaces
- ATA-8 command set

Capacities

- 32, 64, 128, 256 GB

Performance*

- Interface burst read/write: 600 MB/sec
- Sustained read: up to 525 MB/sec
- Sustained write: up to 455 MB/sec
- Random read (4K): up to 86,000 IOPS
- Random write (4K): up to 79,000 IOPS

• Flash Management

- Built-in hardware ECC
- Static/dynamic wear leveling
- Flash bad-block management
- S.M.A.R.T.
- Power Failure Management
- ATA Secure Erase
- TRIM

NAND Flash Type: MLC

• Endurance (in Terabytes Written: TBW)

32GB: 68 TBW64GB: 136 TBW128GB: 272 TBW256 GB: 545 TBW

Temperature ranges

- Operating:

Standard: 0°C to 70°C Extended: -40°C to 85°C Storage: -40°C to 100°C

Supply voltage

 $-5.0 V \pm 5\%$

Power consumption (typical)*

Active mode: 680 mAIdle mode: 50 mA

Form factor

- 2.5"
- Dimensions with 7mm enclosure:
 100.00 x 69.85 x 6.90, unit: mm
- Dimensions with 9.5mm enclosure:
 100.00 x 69.84 x 9.30, unit: mm

Connector

- 7-pin SATA signal connector
- 15-pin SATA power connector

Shock & Vibration**

Shock: 1500 GVibration: 15 G

DRAM cache for enhanced random performance

- SATA power management modes
- Device Sleep mode (optional)
- RoHS compliant
- Thermal sensor (optional)

^{*}The values addressed here are typical and may vary depending on settings and platforms.

^{**}Non-operating



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1. Product Description

1.1 Introduction

Apacer's SFD25A-M is a well-balanced solid-state disk (SSD) drive with standard form factor and great performance. Designed in SATA 6.0 Gbps interface, the SSD is able to deliver exceptional read/write speed, making it the ideal companion for heavy-loading industrial or server operations.

For data efficiency, the internal controlling unit of the SSD is engineered with DRAM for enhanced random performance. In regard of reliability, the drive comes with various implementations including powerful hardware ECC engine, power saving modes, wear leveling, flash block management, S.M.A.R.T., TRIM, and power failure management.

1.2 Capacity Specification

Table 1-1 Capacity specification

| Capacity | Total Bytes* | Cylinders | Heads | Sectors | Max LBA* |
|----------|-----------------|-----------|-------|---------|-------------|
| 32 GB | 32,017,047,552 | 16,383 | 16 | 63 | 62,533,296 |
| 64 GB | 64,023,257,088 | 16,383 | 16 | 63 | 125,045,424 |
| 128 GB | 128,035,676,160 | 16,383 | 16 | 63 | 250,069,680 |
| 256 GB | 256,060,514,304 | 16,383 | 16 | 63 | 500,118,192 |

^{*}Display of total bytes varies from file systems.

1.3 Performance

Table 1-2 Performance specification

| Performance Capacity | 32 GB | 64 GB | 128 GB | 256 GB |
|---------------------------|--------|--------|--------|--------|
| Sustained Read (MB/s) | 380 | 515 | 520 | 525 |
| Sustained Write (MB/s) | 85 | 145 | 300 | 455 |
| Random Read IOPS (4K) | 46,000 | 79,000 | 85,000 | 86,000 |
| Random Write IOPS (4K) | 19,000 | 35,000 | 71,000 | 79,000 |

Note: Performance varies from flash configurations or host system settings.

IOPS: measured on 8GB span (16777216 sectors Disk Size), 32 Outstanding I/Os (QD=32), Full Random Data pattern, 4KB Align I/Os and test durations 15minutes.

^{**}Cylinders, heads or sectors are not applicable for these capacities. Only LBA addressing applies.

LBA count addressed in the table above indicates total user storage capacity and will remain the same throughout the lifespan of the device. However, the total usable capacity of the SSD is most likely to be less than the total physical capacity because a small portion of the capacity is reserved for device maintenance usages.



1.4 Pin Assignments

Table 1-4 describes the SFD signal segment, and Table1-5, power segment.

Figure 1-1 SATA Connectors

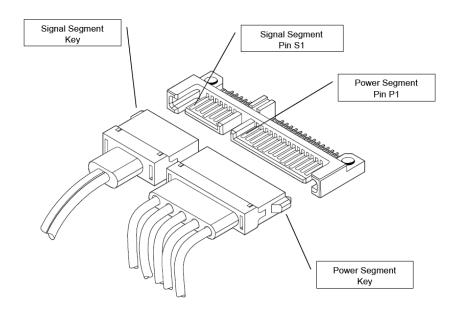


Table 1-4: Signal segment

| Pin | Туре | Description |
|-----|------|--------------------------------|
| S1 | GND | |
| S2 | RxP | + Differential Receive Signal |
| S3 | RxN | - Differential Receive Signal |
| S4 | GND | |
| S5 | TxN | - Differential Transmit Signal |
| S6 | TxP | + Differential Transmit Signal |
| S7 | GND | |

Table 1-5: Power segment

| Pin | Signal/Description |
|-----|-------------------------|
| P1 | Unused (3.3V) |
| P2 | Unused (3.3V) |
| P3 | Unused or Device Sleep* |
| P4 | Ground |
| P5 | Ground |
| P6 | Ground |
| P7 | 5V |
| P8 | 5V |
| P9 | 5V |
| P10 | Ground |
| P11 | DAS |
| P12 | Ground |
| P13 | Unused (12V) |
| P14 | Unused (12V) |
| P15 | Unused (12V) |

^{*}P3 can be configured as Device Sleep trigger by option



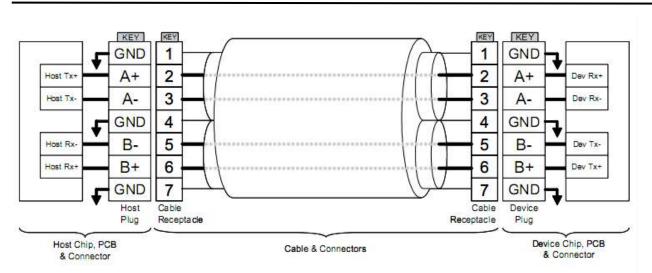


Figure 1-3 SATA Cable/Connector Connection Diagram

The connector on the left represents the Host with TX/RX differential pairs connected to a cable. The connector on the right shows the Device with TX/RX differential pairs also connected to the cable. Notice also the ground path connecting the shielding of the cable to the Cable Receptacle.



2. Software Interface

2.1 Command Set

Table 2-1 summarizes the ATA commands supported by SFD25A-M.

Table 2-1: Command set

| Code | Command | Code | Command |
|-----------|------------------------------|------------|---------------------------|
| E5h | Check Power Mode | F6h | Security Disable Password |
| 90h | Execute Diagnostics | F3h | Security Erase Prepare |
| E7h | Flush Cache | F4h | Security Erase Unit |
| ECh | Identify Device | F5h | Security Freeze Lock |
| E3h | Idle | F1h | Security Set Password |
| E1h | Idle Immediate | F2h | Security Unlock |
| 91h | Initialize Device Parameters | 7xh | Seek |
| C8h | Read DMA | Efh | Set Features |
| 25h | Read DMA EXT | C6h | Set Multiple Mode |
| 60h | Read FPDMA Queued | E6h | Sleep |
| 47h | Read Log DMA EXT | B0h | S.M.A.R.T. |
| 2Fh | Read Log EXT | E2h | Standby |
| C4h | Read Multiple | E0h | Standby Immediate |
| 20 or 21h | Read Sector(s) | Cah | Write DMA |
| 40 or 41h | Read Verify Sector(s) | 35h | Write DMA EXT |
| 10h | Recalibrate | 61h | Write FPDMA Queued |
| 57h | Write Log DMA EXT | 3Fh | Write Log EXT |
| C5h | Write Multiple | 30h or 31h | Write Sector(s) |

2.2 S.M.A.R.T.

S.M.A.R.T. is an abbreviation for Self-Monitoring, Analysis and Reporting Technology, a self-monitoring system that provides indicators of drive health as well as potential disk problems. It serves as a warning for users from unscheduled downtime by monitoring and displaying critical drive information. Ideally, this should allow taking proactive actions to prevent drive failure and make use of S.M.A.R.T. information for future product development reference.

Apacer devices use the standard SMART command B0h to read data out from the drive to activate our S.M.A.R.T. feature that complies with the ATA/ATAPI specifications. S.M.A.R.T. Attribute IDs shall include initial bad block count, total later bad block count, maximum erase count, average erase count, power on hours and power cycle. When the S.M.A.R.T. Utility running on the host, it analyzes and reports the disk status to the host before the device reaches in critical condition.

Note: attribute IDs may vary from product models due to various solution design and supporting capabilities.



Apacer memory products come with S.M.A.R.T. commands and subcommands for users to obtain information of drive status and to predict potential drive failures. Users can take advantage of the following commands/subcommands to monitor the health of the drive.

| Code | SMART Subcommand |
|------|-----------------------------------|
| D0h | READ DATA |
| D1h | READ ATTRIBUTE THRESHOLDS |
| D2h | Enable/Disable Attribute Autosave |
| D4h | Execute Off-line Immediate |
| D5h | Read Log (optional) |
| D6h | Write Log (optional) |
| D8h | Enable Operations |
| D9h | Disable operations |
| Dah | Return Status |

General SMART attribute structure

| Byte | Description |
|-------|-------------|
| 0 | ID (Hex) |
| 1 – 2 | Status flag |
| 3 | Value |
| 4 | Worst |
| 5*-11 | Raw Data |

*Byte 5: LSB

SMART attribute ID list

| ID (Hex) | Attribute Name |
|------------|------------------------------------|
| 9 (0x09) | Power-on hours |
| 12 (0x0C) | Power cycle count |
| 163 (0xA3) | Max. erase count |
| 164 (0xA4) | Avg. erase count |
| 166 (0xA6) | Total later bad block count |
| 167 (0xA7) | SSD Protect Mode (vendor specific) |
| 168 (0xA8) | SATA PHY Error Count |
| 175 (0xAF) | Bad Cluster Table Count |
| 192 (0xC0) | Unexpected Power Loss Count |
| 194 (0xC2) | Temperature |
| 241 (0xF1) | Total sectors of write |



3. Flash Management

3.1 Error Correction/Detection

SFD25A-M implements a hardware ECC scheme, based on the BCH algorithm. It can detect and correct up to 40 bits error in 1K bytes.

3.2 Bad Block Management

Current production technology is unable to guarantee total reliability of NAND flash memory array. When a flash memory device leaves factory, it comes with a minimal number of initial bad blocks during production or out-of-factory as there is no currently known technology that produce flash chips free of bad blocks. In addition, bad blocks may develop during program/erase cycles. When host performs program/erase command on a block, bad block may appear in Status Register. Since bad blocks are inevitable, the solution is to keep them in control. Apacer flash devices are programmed with ECC, block mapping technique and S.M.A.R.T to reduce invalidity or error. Once bad blocks are detected, data in those blocks will be transferred to free blocks and error will be corrected by designated algorithms.

3.3 Wear Leveling

Flash memory devices differ from Hard Disk Drives (HDDs) in terms of how blocks are utilized. For HDDs, when a change is made to stored data, like erase or update, the controller mechanism on HDDs will perform overwrites on blocks. Unlike HDDs, flash blocks cannot be overwritten and each P/E cycle wears down the lifespan of blocks gradually. Repeatedly program/erase cycles performed on the same memory cells will eventually cause some blocks to age faster than others. This would bring flash storages to their end of service term sooner. Wear leveling is an important mechanism that level out the wearing of blocks so that the wearing-down of blocks can be almost evenly distributed. This will increase the lifespan of SSDs. Commonly used wear leveling types are Static and Dynamic.

3.4 Power Failure Management

Power Failure Management plays a crucial role when experiencing unstable power supply. Power disruption may occur when users are storing data into the SSD. In this urgent situation, the controller would run multiple write-to-flash cycles to store the metadata for later block rebuilding. This urgent operation requires about several milliseconds to get it done. At the next power up, the firmware will perform a status tracking to retrieve the mapping table and resume previously programmed NAND blocks to check if there is any incompleteness of transmission.

Note: The controller unit of this product model is designed with a DRAM as a write cache for improved performance and data efficiency. Though unlikely to happen in most cases, the data cached in the volatile DRAM might be potentially affected if a sudden power loss takes place before the cached data is flushed into non-volatile NAND flash memory.

3.5 ATA Secure Erase

ATA Secure Erase is an ATA disk purging command currently embedded in most of the storage drives. Defined in ATA specifications, (ATA) Secure Erase is part of Security Feature Set that allows storage drives to erase all user data areas. The erase process usually runs on the firmware level as most of the ATA-based storage media currently in the market are built-in with this command. ATA Secure Erase can securely wipe out the user data in the drive and protects it from malicious attack.



3.6 TRIM

TRIM is a SATA command that helps improve the read/write performance and efficiency of solid-state drives (SSD). The command enables the host operating system to inform SSD controller whick blocks contain invalid data, mostly because of the erase commands from host. The invalid will be discarded permanently and the SSD will retain more space for itself.

3.7 Thermal Sensor

Apacer Thermal Sensor is a digital temperature sensor with serial interface. By using designated pins for transmission, storage device owners are able to read temperature data.

3.8 SATA Power Management

By complying with SATA 6.0 Gb/s specifications, the SSD supports the following SATA power saving modes:

- ACTIVE: PHY ready, full power, Tx & Rx operational
- PARTIAL: Reduces power, resumes in under 10 μs (microseconds)
- SLUMBER: Reduces power, resumes in under 10 ms (milliseconds)
- HIPM: Host-Initiated Power Management
- DIPM: Device-Initiated Power Management
- AUTO-SLUMBER: Automatic transition from partial to slumber.
- Device Sleep (DevSleep or DEVSLP): PHY powered down; power consumption ≤ 5 mW; host assertion time ≤ 10 ms; exit timeout from this state ≤ 20 ms (unless specified otherwise in SATA Identify Device Log).

Note:

- 1. The behaviors of power management features would depend on host/device settings.
- 2. Device Sleep mode is optional, depending on product ordering selections.



4. Reliability Specifications

4.1 Environmental

SFD25A-M environmental specifications follow MIL-STD-810F, as indicated in the following table.

Table 4-1 SFD25A-M environmental specifications

| Environment | Specification |
|-------------|-------------------------------------------------------------------------------------------|
| | 0°C to 70°C(standard); -40°C to 85°C (extended) |
| Temperature | -40°C to 100°C (Non-operating) |
| Vibration | Non-operating: Sine wave, 15(G), 10~2000(Hz), Operating: Random, 7.69(Grms), 20~2000(Hz) |
| Shock | Non-operating: Acceleration, 1,500 G, 0.5 ms Operating: Peak acceleration, 50 G, 11 ms |

4.2 Mean Time Between Failures (MTBF)

Mean Time Between Failures (MTBF) is predicted based on reliability data for the individual components in SFD drive. The prediction result for the SFD25A-M is more than 1,000,000 hours.

Notes about the MTBF:

The MTBF is predicated and calculated based on "Telcordia Technologies Special Report, SR-332, Issue 2" method.

4.3 Certification and Compliance

SFD25A-M complies with the following standards:

- CE
- FCC
- RoHS
- MIL-STD-810F

4.4 Endurance

The endurance of a storage device is predicted by TeraBytes Written based on several factors related to usage, such as the amount of data written into the drive, block management conditions, and daily workload for the drive. Thus, key factors, such as Write Amplifications and the number of P/E cycles, can influence the lifespan of the drive.

| Capacity | TeraBytes Written |
|----------|-------------------|
| 32 GB | 68 |
| 64 GB | 136 |
| 128 GB | 272 |
| 256 GB | 545 |

Notes:

- The measurement assumes the data written to the SSD for test is under a typical and constant rate.
- The measurement follows the standard metric: 1 TB (Terabyte) = 1000 GB.



5. Electrical Characteristics

5.1 Operating Voltage

Table 5-1 lists the supply voltage for SFD25A-M.

Table 5-1 SFD25A-M operating voltage

| Parameter | Conditions |
|----------------|-----------------------|
| Supply voltage | 5V ±5% (4.75-5.25 V) |

5.2 Power Consumption

Table 5-2 lists the power consumption for SFD25A-M

Table 5-2 Power consumption (typical)

| Mode | 32 GB | 64 GB | 128 GB | 256 GB |
|--------------|-------|-------|--------|--------|
| Active (mA) | 240 | 300 | 470 | 680 |
| Idle (mA) | 50 | 50 | 50 | 50 |

Note: Power consumptions may vary depending on settings and platforms.



6. Mechanical Specifications

6.1 7mm Type Dimensions

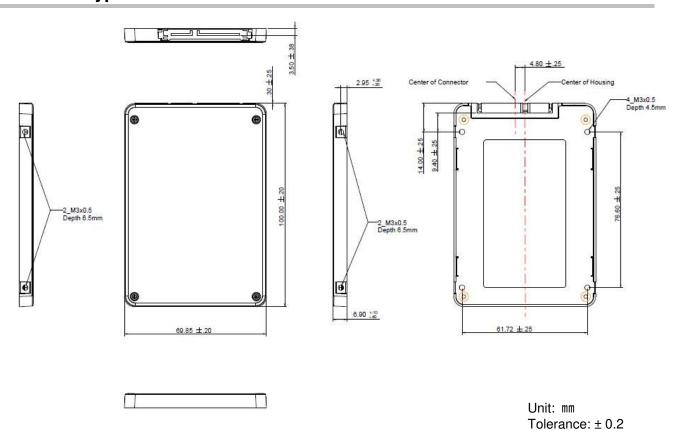
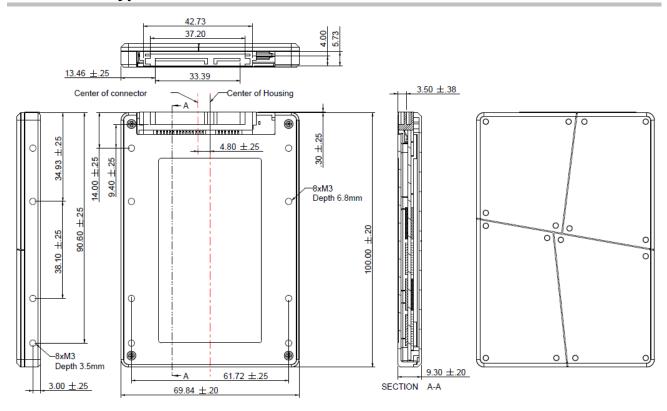


Figure 6-1 SFD25A-M with 7mm Housing physical dimensions



6.2 9.5mm Type Dimensions



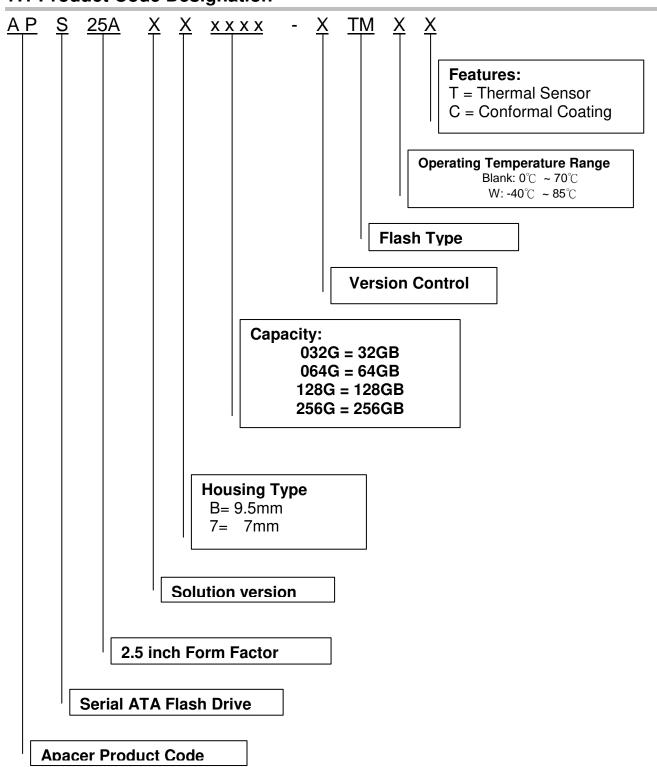
Unit: mm Tolerance: ± 0.2

Figure 6-2 SFD25A-M with 9.5mm Housing physical dimensions



7. Product Ordering Information

7.1 Product Code Designation





7.2 Valid Combination

A. 9.5mm Metal Housing

7.2.1 High Speed / Operating Temperature (0℃ ~ 70℃)

| Capacity | NO DEVSLP | DEVSLP | |
|----------|-------------------|-------------------|--|
| 32GB | APS25A4B032G-3ATM | APS25A4B032G-3BTM | |
| 64GB | APS25A7B064G-3ATM | APS25A7B064G-3BTM | |
| 128GB | APS25A7B128G-3ATM | APS25A7B128G-3BTM | |
| 256GB | APS25A7B256G-3ATM | APS25A7B256G-3BTM | |

7.2.2 High Speed / Operating Temperature (-40° ~ 85°)

| Capacity | NO DEVSLP | DEVSLP | |
|----------|--------------------|--------------------|--|
| 32GB | APS25A4B032G-3ATMW | APS25A4B032G-3BTMW | |
| 64GB | APS25A7B064G-3ATMW | APS25A7B064G-3BTMW | |
| 128GB | APS25A7B128G-3ATMW | APS25A7B128G-3BTMW | |
| 256GB | APS25A7B256G-3ATMW | APS25A7B256G-3BTMW | |

B. 9.5mm Metal Housing + Thermal Sensor

7.2.3 High Speed / Operating Temperature (0℃ ~70℃)

| Capacity | NO DEVSLP | DEVSLP | |
|----------|--------------------|--------------------|--|
| 32GB | APS25A4B032G-3ATMT | APS25A4B032G-3BTMT | |
| 64GB | APS25A7B064G-3ATMT | APS25A7B064G-3BTMT | |
| 128GB | APS25A7B128G-3ATMT | APS25A7B128G-3BTMT | |
| 256GB | APS25A7B256G-3ATMT | APS25A7B256G-3BTMT | |

7.2.4 High Speed / Operating Temperature (-40° ~ 85°)

| Capacity | NO DEVSLP | DEVSLP |
|----------|---------------------|---------------------|
| 32GB | APS25A4B032G-3ATMTW | APS25A4B032G-3BTMTW |
| 64GB | APS25A7B064G-3ATMTW | APS25A7B064G-3BTMTW |
| 128GB | APS25A7B128G-3ATMTW | APS25A7B128G-3BTMTW |
| 256GB | APS25A7B256G-3ATMTW | APS25A7B256G-3BTMTW |
| | | |



C. 7mm Plastic Housing

7.2.5 High Speed / Operating Temperature (0° ~ 70°)

| Capacity | NO DEVSLP | DEVSLP | |
|----------|-------------------|-------------------|--|
| 32GB | APS25A47032G-3ATM | APS25A47032G-3BTM | |
| 64GB | APS25A77064G-3ATM | APS25A77064G-3BTM | |
| 128GB | APS25A77128G-3ATM | APS25A77128G-3BTM | |
| 256GB | APS25A77256G-3ATM | APS25A77256G-3BTM | |

7.2.6 High Speed / Operating Temperature (-40° ~ 85°)

| Capacity | NO DEVSLP | DEVSLP | |
|----------|--------------------|--------------------|--|
| 32GB | APS25A47032G-3ATMW | APS25A47032G-3BTMW | |
| 64GB | APS25A77064G-3ATMW | APS25A77064G-3BTMW | |
| 128GB | APS25A77128G-3ATMW | APS25A77128G-3BTMW | |
| 256GB | APS25A77256G-3ATMW | APS25A77256G-3BTMW | |

D. 7mm Plastic Housing + Thermal Sensor

7.2.7 High Speed / Operating Temperature (0℃ ~ 70℃)

| Capacity | NO DEVSLP | DEVSLP | |
|----------|--------------------|--------------------|--|
| 32GB | APS25A47032G-3ATMT | APS25A47032G-3BTMT | |
| 64GB | APS25A77064G-3ATMT | APS25A77064G-3BTMT | |
| 128GB | APS25A77128G-3ATMT | APS25A77128G-3BTMT | |
| 256GB | APS25A77256G-3ATMT | APS25A77256G-3BTMT | |

7.2.8 High Speed / Operating Temperature (-40° ~ 85°)

| Capacity | NO DEVSLP | DEVSLP | |
|----------|---------------------|---------------------|--|
| 32GB | APS25A47032G-3ATMTW | APS25A47032G-3BTMTW | |
| 64GB | APS25A77064G-3ATMTW | APS25A77064G-3BTMTW | |
| 128GB | APS25A77128G-3ATMTW | APS25A77128G-3BTMTW | |
| 256GB | APS25A77256G-3ATMTW | APS25A77256G-3BTMTW | |

Note: Valid combinations are those products in mass production or will be in mass production. Consult your Apacer sales representative to confirm availability of valid combinations and to determine availability of new combinations.



Revision History

| Revision | Description | Date |
|----------|----------------------------------------------------------------------------|------------|
| 0.1 | Preliminary release | 05/17/2013 |
| 0.2 | Updated mechanical drawings | 08/30/2013 |
| 0.3 | Added performance and power consumption information for 64, 128 and 256 GB | 09/05/2013 |
| 0.4 | Added IOPS | 10/11/2013 |
| | Integrates categories of standard and high-speed types | |
| 1.0 | Official release | 11/07/2013 |
| 1.1 | Updated performance and power consumption due to changes in components | 11/21/2013 |
| 1.2 | Added Device Sleep option to power segment pin3 | 12/16/2013 |
| | Updated 7mm type mechanical specifications | |
| | Added Endurance (TBW) section | |
| 1.3 | Added Enhanced temperature grade into the specifications | 04/21/2014 |
| 1.4 | Updated performance and power consumption due to firmware upgrade | 05/17/2014 |
| 1.5 | Corrected 16GB part numbers for 9.5mm housing with standard speed models | 06/26/2014 |
| 1.6 | Added Thermal Sensor feature | 09/19/2014 |
| 1.7 | Removed Standard type and enhanced temperature grade support | 04/07/2015 |
| 1.8 | Revised product ordering information - added extended temperature support | 08/21/2015 |



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